

# Sintering process of $Y_2O_3$ -added $Si_3N_4$

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The sintering process of  $Y_2O_3$ -added  $Si_3N_4$  has been investigated by dilatometry and microstructural observations. Densification was promoted above 1440°C by the formation of eutectic melts in the  $Y_2O_3$ - $SiO_2$ - $Si_3N_4$  triangle. However, the dilatometric curves indicated no shrinkage corresponding to the rearrangement process, despite liquid-phase sintering. The kinetic order for the initial-stage sintering was 0.47 to 0.49. These values indicated that the phase-boundary reaction was rate controlling. The apparent activation energy (323 kJ mol<sup>-1</sup>) was smaller than the dissociation energy for the Si-N bond (435 kJ mol<sup>-1</sup>). ESR data and lattice strain indicated that the disordered crystalline structure of the  $Si_3N_4$  starting powder promoted the reaction of  $Si_3N_4$  with eutectic melts. After a period of initial-stage sintering, the formation of fibrous  $\beta$ - $Si_3N_4$  grains resulted in interlocked structures to interrupt the densification.

## 1. Introduction

Silicon nitride ceramics are expected to be high-temperature structural materials because of their high strength and high fracture toughness [1, 2]. The high fracture toughness is attained by the twinned fibrous grains formed in the sintered bodies during liquid-phase sintering [3]. However, the glassy grain boundary phases degrade strength at elevated temperatures [4, 5]. On the other hand, when preparing sintered bodies with only a small amount of glassy phases by solid-state reaction sintering [6] or hot isostatic pressing (HIP) without oxide additives [7], the resulting equiaxial grains considerably degrade the fracture toughness. Therefore the sintering process must be further optimized according to kinetic information for grain growth and densification.

Many studies have been carried out on the kinetics of densification and  $\alpha/\beta$  transformation of  $Si_3N_4$  [8-17]. However, some processes in kinetics and reactions have not been yet clarified. For example, Hampshire and Jack [10] have shown that the densification of  $Y_2O_3$ -added  $Si_3N_4$  progressed through a diffusion-rate-controlling sintering after a rearrangement process. Instead, Babini *et al.* [17] have suggested a boundary-reaction rate-controlling mechanism for the hot pressing of  $Y_2O_3$ - $Si_3N_4$ - $SiO_2$  system, where the solution of  $Si_3N_4$  into the melts was the rate-determining step. Such contradictions, which can also be found in studies of MgO-added  $Si_3N_4$  [8, 10, 11], require precise measurements of shrinking behaviour. Therefore in this study shrinkage and shrinking rate of  $Y_2O_3$ -added  $Si_3N_4$  were measured precisely by using a specially assembled high-temperature dilatometer. Kinetic parameters were discussed in relation to the microstructure.

## 2. Experimental procedure

### 2.1. Materials

High-purity  $\alpha$ - $Si_3N_4$  powder (Denka Co. Ltd, Tokyo, grade SNGX) was used as a starting material. The

metallic impurity (15 elements), oxygen content and specific surface area were 227 p.p.m., 1.02 wt % and 15.3 m<sup>2</sup> g<sup>-1</sup>, respectively. This powder was synthesized by nitridation of silicon powder and consisted of irregularly shaped particles. Yttria powder (Hokko Chemicals Co. Ltd, Tokyo) with a specific surface area of 70.9 m<sup>2</sup> g<sup>-1</sup> was used as a sintering aid. A powder mixture containing 6 mol %  $Y_2O_3$  was prepared by wet mixing in methanol using a vibration ball mill. Drying was performed at 150°C under vacuum after evaporating the methanol at 80°C in a flow of N<sub>2</sub> gas (0.3 kPa). Mechanically prepressed green bodies (9 × 9 × 40 mm, 5 MPa) were isostatically pressed at 500 MPa. The green density was 1.94 ± 0.03 g cm<sup>-3</sup>.

### 2.2. Equipment and procedure

The shrinking rate was measured by a high-temperature dilatometer as shown in Fig. 1. The maximum temperature and gas pressure applicable were 2300°C and 1.0 MPa, respectively. The shrinkage and shrinking rate of the samples and of a reference material (re-crystallized SiC, RCSC) were detected by transducers with a time resolution of 1 sec. To prevent the contamination of samples by carbon, most of the parts inside the heater were made of RCSC. The detection errors of shrinkage and shrinking rate were less than 1.78 × 10<sup>-2</sup>% and 3.2 × 10<sup>-3</sup>% min<sup>-1</sup>, respectively. Details of the equipment have been discussed previously [18].

The temperature dependencies of shrinkage and shrinking rate were measured at 2 to 50 K min<sup>-1</sup> in a N<sub>2</sub> atmosphere. Isothermal measurement was performed at a heating rate of 50 K min<sup>-1</sup> at variable temperatures in the range 1525 to 1850°C. The applied load, gas pressure and gas-flow rate were 10 g, 1.0 MPa and 1.0 dm<sup>3</sup> min<sup>-1</sup>, respectively.

The dilatometric measurements, bulk density and porosity were determined by Archimedes' principle. Microstructure was observed by scanning electron microscopy (SEM, JEOL JSM-T-330AS). Grain-

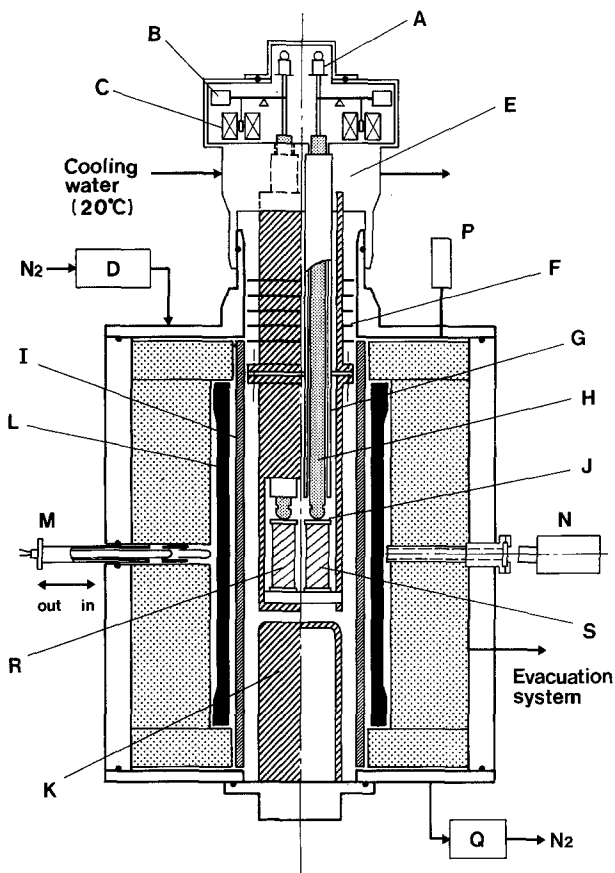


Figure 1 Inside view of high-temperature dilatometer, A, weight; B, counter-weight; C, transducer; D, gas-pressure controller; E, temperature-controlled block; F, radiation shield; G, sleeve; H, detector; I, shield tube; J, spacer; K, heat sink; L, heater; M, thermocouple (Pt-Rh); N, optical pyrometer; P, pressure gauge; Q, gas-flow-rate controller; R, reference; S, sample.

boundary phases were identified by X-ray diffractometry with  $\text{CuK}\alpha$  radiation (40 kV, 100 mA).

### 3. Results

#### 3.1. Temperature dependence of shrinkage and shrinking rate

Figs 2 and 3 show the temperature dependence of shrinkage ( $\Delta L/L_0$ ) and shrinking rate ( $d(\Delta L/L_0)/dt v^{-1}$ ,  $v$  = heating rate), respectively. The dependence of commercially available  $\text{Si}_3\text{N}_4$  (H.C. Starck, LC-12) was also measured for comparison. The final

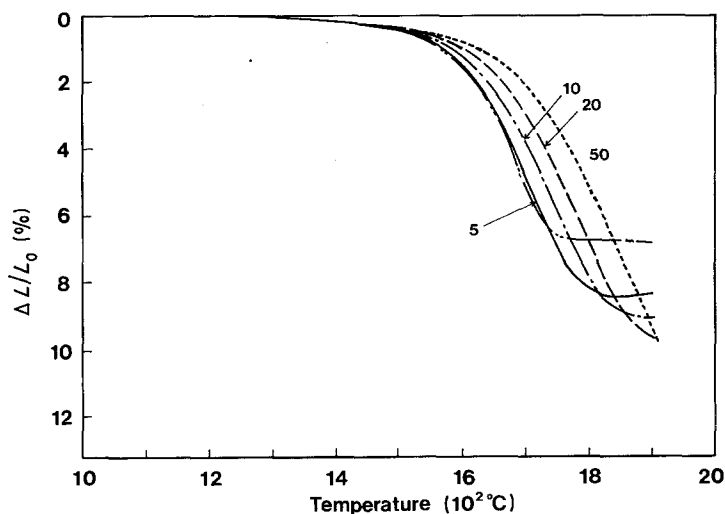


Figure 2 Temperature dependence of shrinkage ( $\Delta L/L_0$ ). Heating rate,  $2 \text{ K min}^{-1}$ .

shrinkage in the transverse direction of the samples agreed well with the determined shrinkage in the lengthwise direction.

Figs 2 and 3 indicate that the densification progressed above the lowest eutectic temperature of the  $\text{Y}_2\text{O}_3\text{-SiO}_2\text{-Si}_3\text{N}_4$  triangle ( $1440^\circ\text{C}$ ) [10]. The sinterability of the SNGX powder was somewhat improved compared with LC-12. However, the shrinkage corresponding to the rearrangement processes hardly appeared in spite of the liquid-phase sintering. The curves for the SNGX powder in both figures shifted toward higher temperatures with the increase in  $v$ . The final shrinkage at  $1900^\circ\text{C}$  decreased with decreasing heating rate because of the termination of shrinking at low temperatures. A slight expansion appeared around  $1850^\circ\text{C}$  at 2 to  $10 \text{ K min}^{-1}$ . The shrinking rate increased again above  $1850^\circ\text{C}$  at 2 and  $5 \text{ K min}^{-1}$  after expansion. The termination of densification was caused by the growth of fibrous grains as shown in Fig. 4. The body sintered at  $2 \text{ K min}^{-1}$  consisted of elongated large grains. The grain size was reduced with the increase in heating rate. The formation of the interlocked structures of large fibrous grains during sintering resulted in the termination of densification. The remarkably low shrinkage at  $2 \text{ K min}^{-1}$  could also be related to the thermal decomposition of the sample as described by Mitomo *et al.* [8], since the weight loss at  $2 \text{ K min}^{-1}$  was 7.34%, while it was less than 4.65% for the other samples.

#### 3.2. Isothermal shrinkage and properties of heat-treated samples

Fig. 5 shows the isothermal shrinkage as a function of soaking time,  $t$ . The shrinkages at  $1525$  to  $1750^\circ\text{C}$  continuously increased with increasing soaking time. However, at  $1850^\circ\text{C}$  the shrinkage decreased for soaking times of 5 to 15 min and then slightly increased, as expected from Figs 2 and 3.

Fig. 6 shows the X-ray diffraction profiles of heat-treated samples. The  $\alpha\text{-Si}_3\text{N}_4$  contents are listed in Table I with other properties. At  $1525$  to  $1600^\circ\text{C}$ ,  $\text{Y}_2\text{O}_3 \cdot \text{Si}_3\text{N}_4$  (N-melilite) was only identified as the grain-boundary phase. The intensity of reflections for N-melilite weakened above  $1700^\circ\text{C}$  and disappeared at  $1725^\circ\text{C}$ . Reflections of  $10\text{Y}_2\text{O}_3 \cdot 9\text{SiO}_2 \cdot \text{Si}_3\text{N}_4$

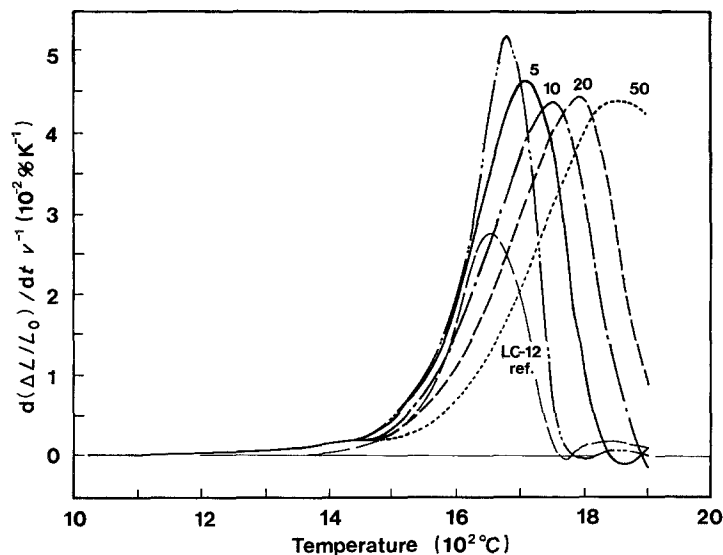


Figure 3 Temperature dependence of shrinkage rate divided by heating rate  $[(\Delta L/L_0)/dt v^{-1}]$ .  $v = 2 \text{ K min}^{-1}$ .

(N-apatite) appeared above  $1650^\circ\text{C}$ . Reflections similar to those of  $4\text{Y}_2\text{O}_3 \cdot \text{SiO}_2 \cdot \text{Si}_3\text{N}_4$  (N-wohlerite) appeared at  $1850^\circ\text{C}$ . However, the formation of N-wohlerite was not reliable. Table I indicated that the  $\alpha/\beta$  transformation was very slow at  $1525$  to  $1600^\circ\text{C}$  and was remarkably promoted above  $1650^\circ\text{C}$ .

The fracture surface of heat-treated samples is shown in Fig. 7. The small particles of less than  $0.1 \mu\text{m}$  in the starting powder were consumed, and spherical or roundish grains with a smooth surface were formed at  $1525$  to  $1600^\circ\text{C}$ . The limited formation of fibrous grains below  $1600^\circ\text{C}$  agreed well with the slow transformation rate at that temperature range. At  $1650$  to  $1675^\circ\text{C}$ , the grains grew with the transformation. The aspect ratio was very small up to  $1700^\circ\text{C}$ . Fibrous grains were evidently developed above  $1725^\circ\text{C}$  (compare the microstructure at  $1700^\circ\text{C}$  with that at  $1725^\circ\text{C}$ ).

### 3.3. Kinetic parameters

The microstructure shows spherical or roundish grains with low aspect ratio at  $1525$  to  $1725^\circ\text{C}$ . This satisfied the assumption in Kingery's model [19, 20] for application to the shrinking behaviour shown in Fig. 5. The kinetic order ( $n$ ) in Kingery's expression, Equation 1 below, was obtained from the log-log plots shown in Fig. 8, assuming that the increase of  $r$  was negligible.

$$\Delta L/L_0 = kr^{-m}t_c^{-n} \quad (1)$$

where  $k$  is a kinetic constant,  $r$  = grain radius,  $t_c$  = corrected soaking time, and  $m, n$  are constants, where the soaking time ( $t$ ) was corrected according to an approximately linear relation between  $t$  and  $\log(\Delta L/L_0)$  within 2 min after attaining the test temperatures. The shrinkage ( $\Delta L/L_0$ ) was not corrected, since the shrinkage of rearrangement process was negligibly small as shown in Figs 2 and 3.

The kinetic order ( $n$ ) listed in Table I was 0.47 to 0.49 at  $1525$  to  $1625^\circ\text{C}$ . These values were close to the 0.50 expected for the boundary-reaction-controlling mechanism for spherical grains. The kinetic constant ( $k$ ) in Equation 1 was obtained by plotting  $\Delta L/L_0$  against  $t^{-0.5}$ . The activation energy obtained from the Arrhenius plot shown in Fig. 9 was  $323 \text{ kJ mol}^{-1}$ .

## 4. Discussion

### 4.1. Densification process

The densification took place without indicating a rearrangement process in the initial sintering. This meant that the rates of reactions of  $\text{Si}_3\text{N}_4$  with the liquid phase or diffusion was faster than that of particle migration. It was considered that the high viscosity of  $\text{Y}_2\text{O}_3\text{-SiO}_2$  melts [10, 21] resulted in increased resistance to particle migration. The irregular shape and wide distribution of particle size of the starting powder may also have suppressed the migration.

TABLE I Properties of heat-treated compacts

Temperature ( $^\circ\text{C}$ )	Time (h)	Bulk density ( $\text{g cm}^{-3}$ )	Porosity (%)		Weight loss (%)	$\alpha$ -Phase content* (%)	Kinetic order
			Closed	Open			
1525	3	2.10	2.1	35.1	1.49	95.6	0.449
1550	3	2.21	2.1	35.0	1.67	87.7	0.467
1575	3	2.31	2.2	28.1	2.34	84.3	0.471
1600	3	2.35	2.3	27.0	3.14	77.4	0.487
1650	3	2.45	2.3	24.2	4.07	26.0	0.472
1675	2	2.49	2.5	23.0	3.74	18.3	0.477
1700	3	2.52	2.3	22.4	4.57	6.8	0.432
1725	3	2.49	2.2	23.1	5.11	5.1	0.431
1750	2	2.54	2.6	21.2	4.91	0	0.406
1850	1	2.53	2.7	21.7	6.72	0	-

\* Obtained as a fractional peak intensity of  $\alpha\text{-Si}_3\text{N}_4$  to the sum of  $\alpha\text{-Si}_3\text{N}_4$  [(102) + (210) reflections] and  $\beta\text{-Si}_3\text{N}_4$  [(101) + (210) reflections].

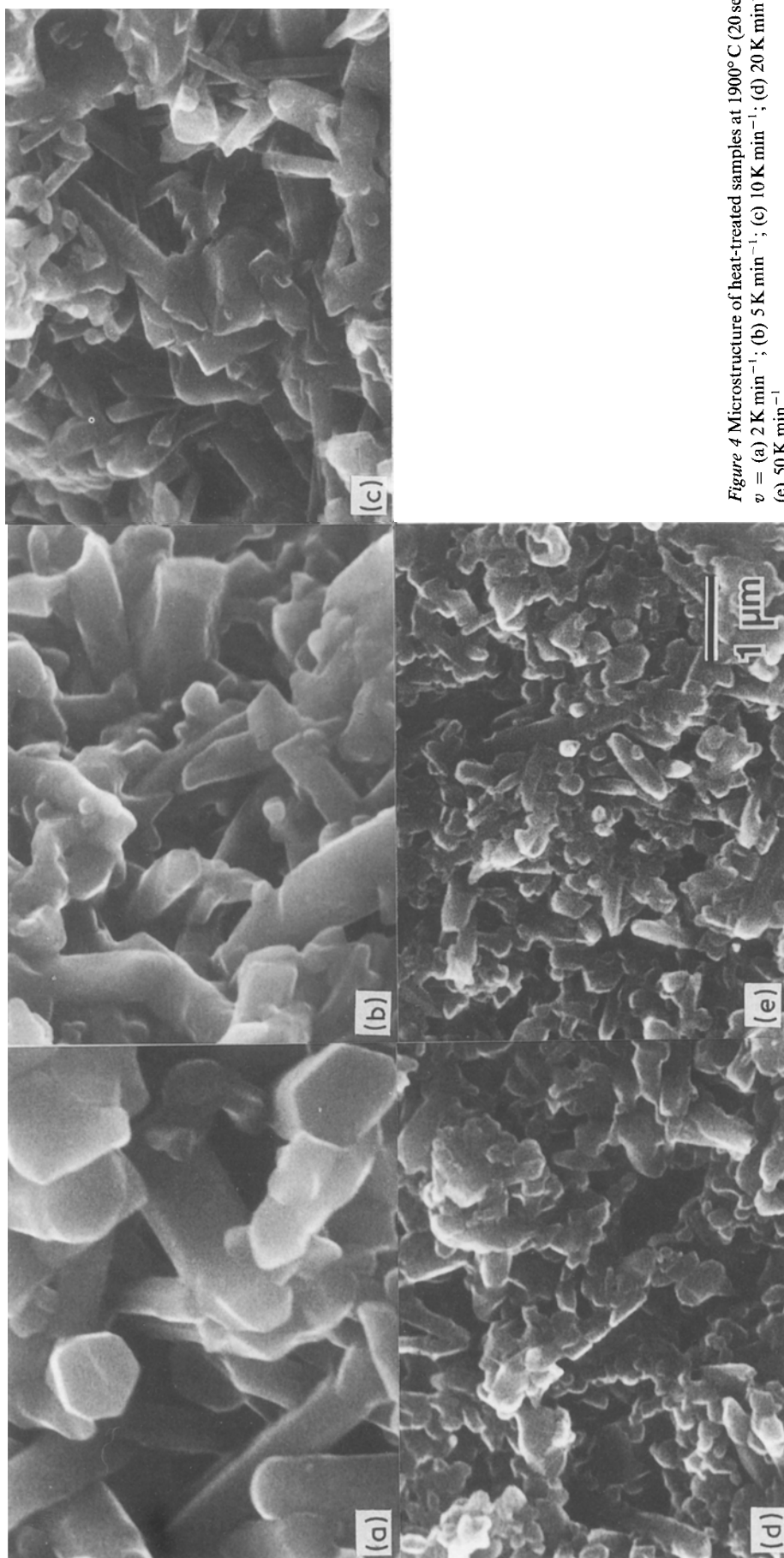


Figure 4 Microstructure of heat-treated samples at 1900°C (20 sec).  
 $v =$  (a) 2 K min<sup>-1</sup>; (b) 5 K min<sup>-1</sup>; (c) 10 K min<sup>-1</sup>; (d) 20 K min<sup>-1</sup>;  
(e) 50 K min<sup>-1</sup>.

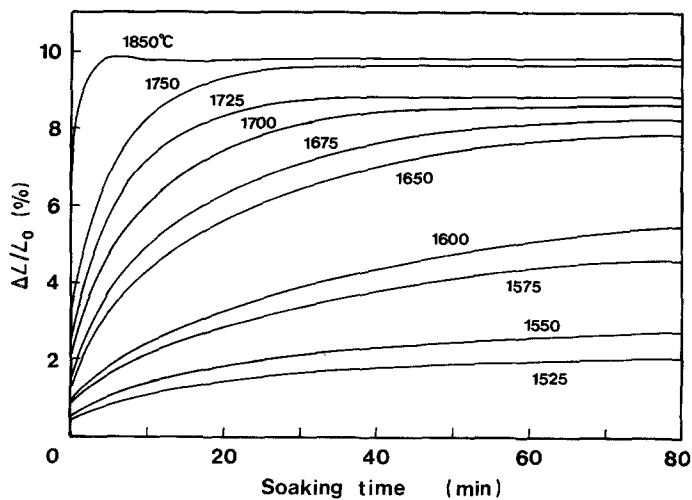


Figure 5 Isothermal shrinkage.

The kinetic order at 1525 to 1725°C indicated the boundary reaction-rate-controlling sintering. The activation energy ( $\Delta E = 323 \text{ kJ mol}^{-1}$ ) was comparable with the Si-N bond strength ( $435 \text{ kJ mol}^{-1}$ ) [22] when considering the improved sinterability of the SNGX powder. The value of  $\Delta E$  was greater than the activation energy of the diffusion of N atoms in  $\text{SiO}_2$  glass ( $108 \text{ kJ mol}^{-1}$ ) [23]. This supported the reaction-rate-controlling mechanism, although the grain-boundary phase contained  $\text{Y}_2\text{O}_3$ . The low activation energy for diffusion did not contradict the high viscosity suppressing the rearrangement process, since the activation energy for viscous flow was usually higher than that for diffusion [24].

The kinetic order decreased below 1550°C and above 1700°C as shown in Table I. It was thought that the decrease at higher temperatures was caused by the growth of prismatic grains. Since the kinetic order for

reaction-controlling densification of prismatic grains was 0.33 [18, 19]. At lower temperatures, the kinetic order may be related to the decrease of the ultrafine particles less than  $0.1 \mu\text{m}$  and the change in powder shape (irregular to roundish).

#### 4.2. Characteristics of sinterable powder

The peculiarities of powders produced by nitridation-milling processes are the large specific surface area, irregularity in particle shape and the increase of the lattice strain. The large excess energy stored in powder particles is responsible for the increased reaction ability of  $\text{Si}_3\text{N}_4$  with melts [25]. Somiya *et al.* [26] showed that the particles of the SNGX powder were covered by an amorphous surface layer, and that the lattice strain was relatively large for the SNGX powder. By electron spin resonance spectrometry (ESR) it was found that the radical concentration also increased for the SNGX powder ( $2.46 \times 10^4 \text{ counts g}^{-1}$ ) compared with the LC-12 powder ( $2.02 \times 10^3 \text{ counts g}^{-1}$ ). These characteristics of the SNGX powders indicate a disordered crystalline structure resulting in increased reaction ability and, therefore, a decrease of  $\Delta E$  from the dissociation energy of the Si-N bond.

#### 4.3. Grain growth

After the initial sintering, the grain growth interrupted the densification, especially when fibrous grains formed. To obtain the apparent activation energy ( $\Delta E_a$ ), including the influence of grain growth, the temperature dependence in Fig. 2 was replotted by the Ozawa-Doyle technique [27, 28]. In this technique, the  $\Delta E_a$  was obtained by the following relation irrespective of the reaction mechanism:

$$\log v = (\text{const}) - 0.4567 \Delta E_a / RT \quad (2)$$

Fig. 10 shows the Ozawa-Doyle plots. Linear relations were obtained for shrinkages ranging from 4 to 7%. The  $\Delta E_a$  calculated in this way was 763 to  $814 \text{ kJ mol}^{-1}$ , which was considerably higher than the  $\Delta E$  for Kingery's model and the dissociation energy of the Si-N bond. The reason was that the Ozawa-Doyle plot corresponded to the Arrhenius plot of a suspected kinetic constant ( $k_a = kr^{-m}$ ) instead of the real kinetic constant ( $k$ ). The interrupting effect of densification by grain growth was estimated by using the following

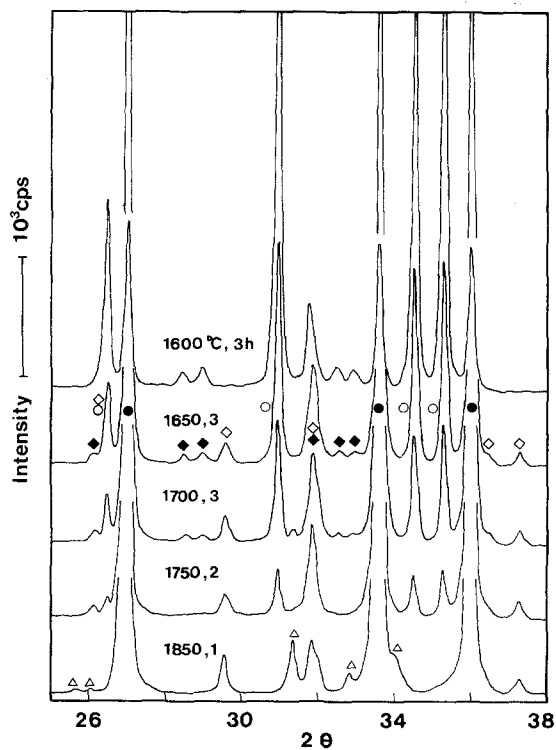


Figure 6 X-ray-diffraction patterns after isothermal dilatometry.  $\circ$ ,  $\alpha$ - $\text{Si}_3\text{N}_4$ ;  $\bullet$ ,  $\beta$ - $\text{Si}_3\text{N}_4$ ;  $\blacklozenge$ ,  $\text{Y}_2\text{O}_3 \cdot \text{Si}_3\text{N}_4$ ;  $\diamond$ ,  $10\text{Y}_2\text{O}_3 \cdot 9\text{SiO}_2 \cdot \text{Si}_3\text{N}_4$ ;  $\triangle$ , unknown (may be  $4\text{Y}_2\text{O}_3 \cdot \text{SiO}_2 \cdot \text{Si}_3\text{N}_4$ ).

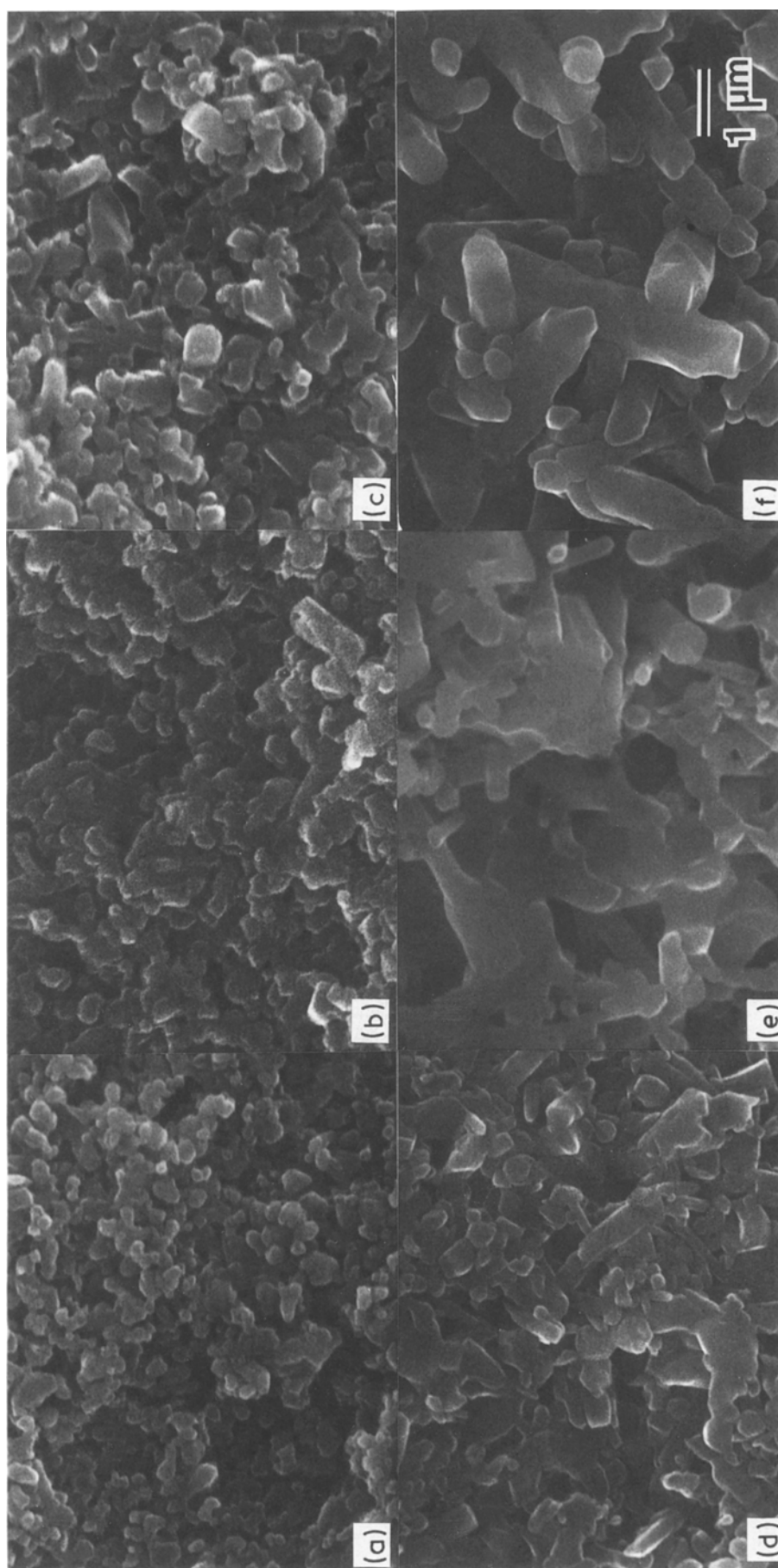


Figure 7 Microstructure of samples after isothermal dilatometry. (a) 1600°C, 3 h; (b) 1650°C, 3 h; (c) 1675°C, 2 h; (d) 1700°C, 3 h; (e) 1725°C, 3 h; (f) 1850°C, 1 h.

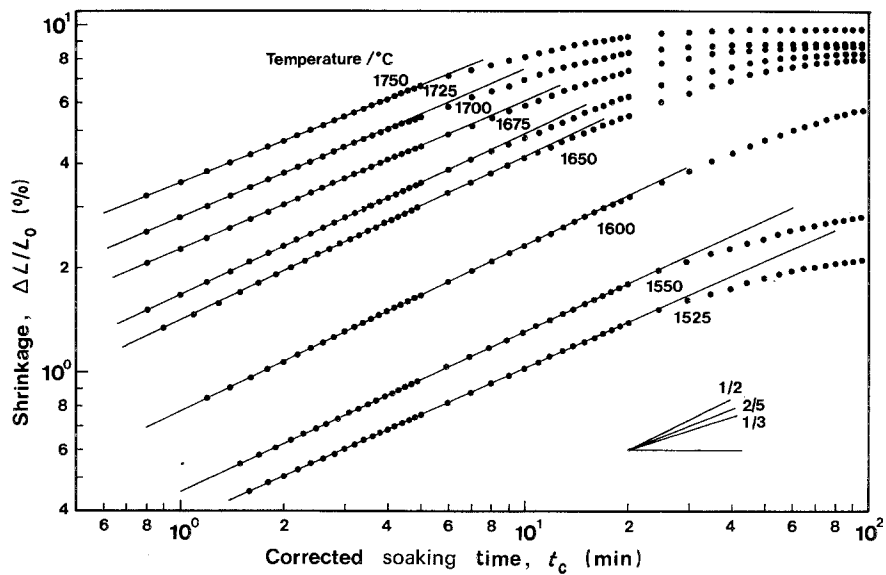


Figure 8 Log-log plots of shrinkage against corrected soaking time.

Figure 9 Arrhenius plot for the initial sintering of  $Y_2O_3$ -doped  $Si_3N_4$ .

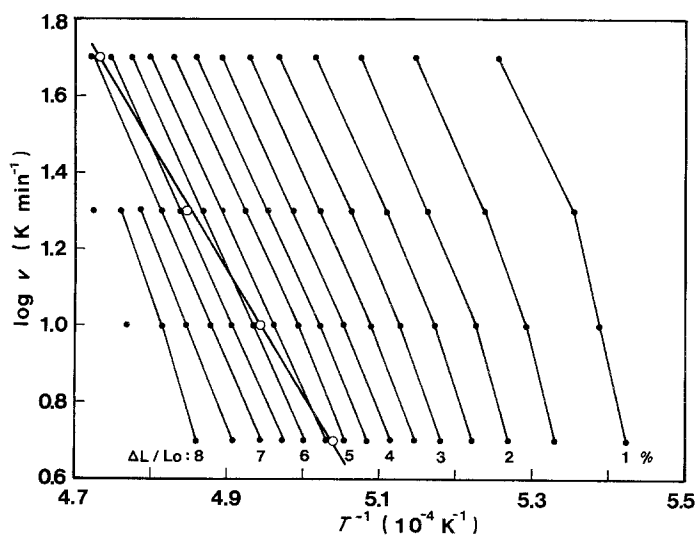
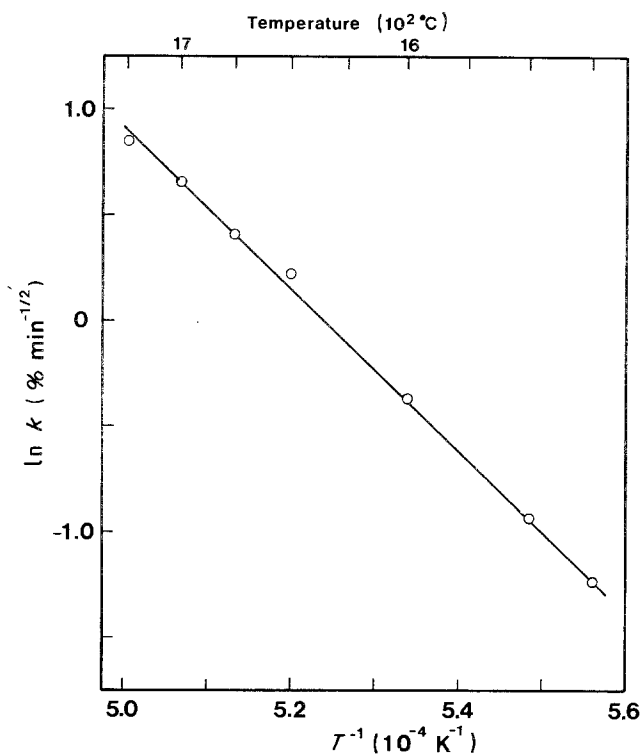


Figure 10 Ozawa-Doyle plots. Open circles indicate peak temperatures of shrinking rate.

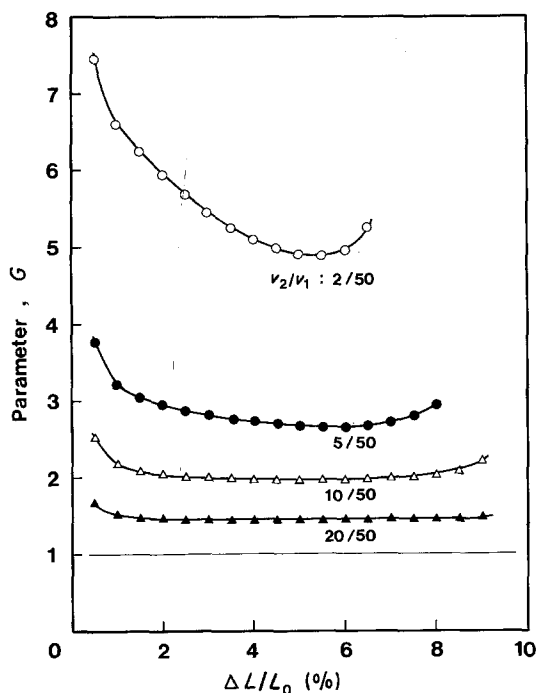


Figure 11 Parameter  $G$  indicating the interrupting effect on densification derived by the modified Ozawa-Doyle technique.

equation:

$$\begin{aligned} \Delta E_a &= R \frac{\ln(k_1 r_1^{-m}) - \ln(k_2 r_2^{-m})}{T_2^{-1} - T_1^{-1}} \\ &= R \frac{\ln(k_1/k_2) + mR \ln(r_2/r_1)}{T_2^{-1} - T_1^{-1}} \quad (3) \end{aligned}$$

By substituting the term  $[R \ln(k_1/k_2)/(T_2^{-1} - T_1^{-1})]$  by  $\Delta E$ , Equation 4 was obtained:

$$\begin{aligned} G &= r_2/r_1 \\ &= \exp [(\Delta E_a - \Delta E) (T_2^{-1} - T_1^{-1}) m^{-1} R^{-1}] \quad (4) \end{aligned}$$

Practically, the parameter  $G$  indicates the overall interruption to densification by grain growth, change in grain shape (roundish to prismatic) and thermal decomposition between  $T_1$  and  $T_2$ . From the Ozawa-Doyle plots, the parameter  $G$  was obtained as the difference of shrinking behaviour between two heating rates at individual shrinkages. Fig. 11 shows the parameter  $G$  at 2, 5, 10 and 20  $\text{K min}^{-1}$  against 50  $\text{K min}^{-1}$  as a function of shrinkage, assuming  $m$  to be unity for the boundary reaction rate controlling. The final value of the parameter  $G$  was 5.3, 2.6, 2.1 and 1.5 for 2, 5, 10 and 20  $\text{K min}^{-1}$ , respectively. These values agreed with the ratio of grain size at  $v$  to 50  $\text{K min}^{-1}$  in transverse direction, as shown in Fig. 4. This indicates that the influence of grain growth was greater at lower heating rates, and that the influence of the change in grain shape was almost the same for every heating rate, at least at high shrinkages. At the initial-stage sintering, the parameter was considerably higher at the low heating rate. This may be caused by the influence of the change in grain shape and the consumption of ultrafine particles.

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